

1214-32L 32 Watts, 36 Volts Pulsed Radar at 1.2-1.4 GHz

## **GENERAL DESCRIPTION**

The 1214-32L is an internally matched, COMMON BASE transistor capable of providing 32 Watts of pulsed RF output power at 5 milliseconds pulse width, 20% duty factor across the band 1200 to 1400 MHz. This hermetically soldersealed transistor is specifically designed for LBand radar applications. It utilizes gold metallization and diffused emitter ballasting to provide high reliability and supreme ruggedness.

### ABSOLUTE MAXIMUM RATINGS

<b>Maximum Power Dissipation</b> Device Dissipation @ 25°C <sup>1</sup> <b>Maximum Voltage and Current</b>	125 W
Collector to Base Voltage (BV <sub>ces</sub> ) Emitter to Base Voltage (BV <sub>ebo</sub> ) Collector Current (I <sub>c</sub> ) Maximum Temperatures	50 V 3.5 V 5 A
Storage Temperature -65 to Operating Junction Temperature	to +200 °C +200 °C

CASE OUTLINE 55AW-1

#### **ELECTRICAL CHARACTERISTICS @ 25°C**

SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN	ТҮР	MAX	UNITS
P <sub>out</sub> <sup>1</sup> Power Output		F = 1200-1400 MHz			41	W
Pg Power Gain		Pin = 5.3 W	7.8		8.9	dB
$\eta_c$	Collector Efficiency	Pulse Width = $5 \text{ mS}$	42	45		%
R <sub>L</sub> Return Loss		Duty Factor = 20%	-9			dB
Pd Pulse Droop					0.5	dB
VSWR <sup>1</sup>	Load Mismatch Tolerance <sup>1</sup>	F=1200 MHz, Pin=5.3 W			3.0:1	

#### FUNCTIONAL CHARACTERISTICS @ 25°C

BV <sub>ebo</sub>	Emitter to Base Breakdown	Ie = 15 mA	3.5		V
BV <sub>ces</sub>	Collector to Emitter Breakdown	Ic = 100 mA	50		V
h <sub>FE</sub>	DC – Current Gain	Vce = 5V, Ic = 1A	20		
$\theta jc^1$	Thermal Resistance			1.4	°C/W

NOTES: 1. Pulse condition of 5 mS, 20%

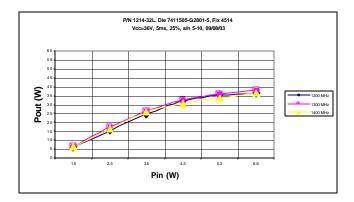
Rel 5: March 2005

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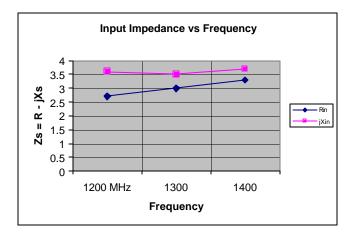
# 1214-32L

## Performance Curves

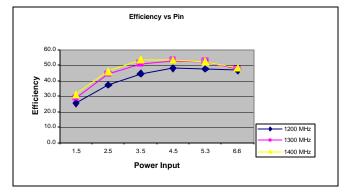
## **Power Output vs Power Input**



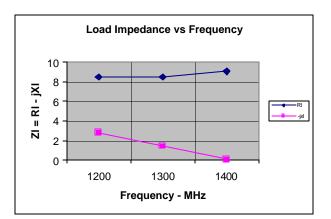
## **Input Impedance**

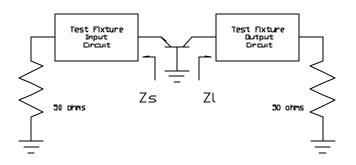


## **Efficiency vs Power Input**



## Load Impedance



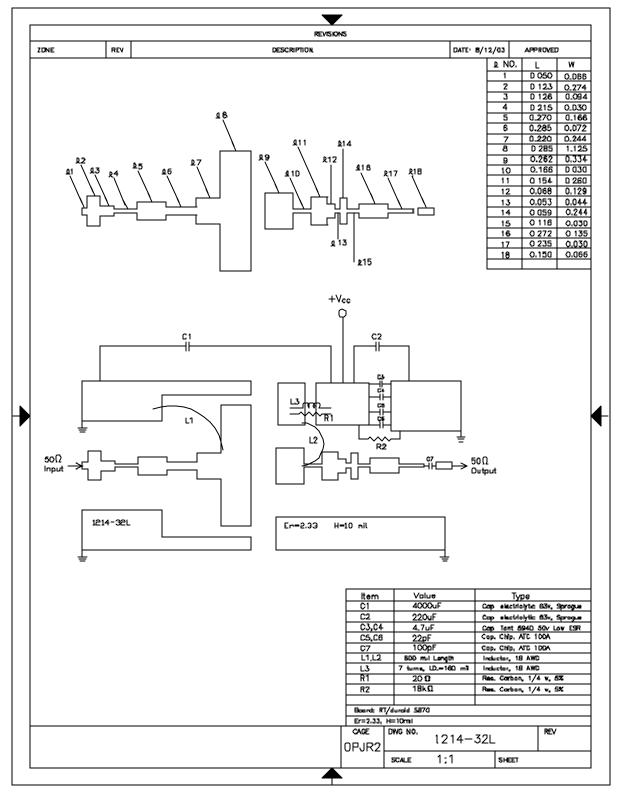


Impedance		
Freq	Zs	ZI
1200	2.7-j3.6	8.5-j2.8
1300	3-j3.5	8.5-j1.44
1400	3.3-j3.7	9.07-j0.08

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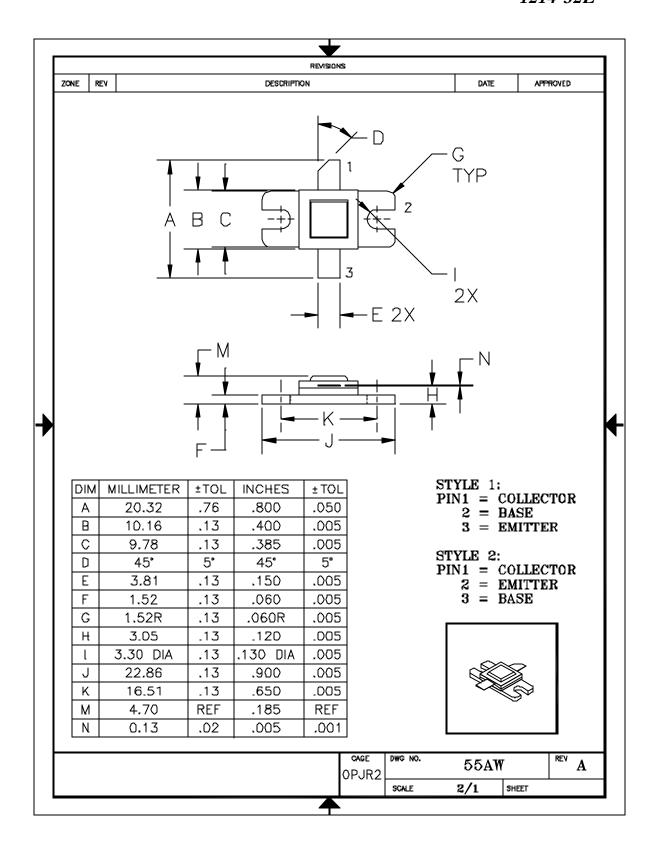
#### 1214-32LR5

### 1214-32L



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1214-32LR5

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